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APPLICATION NO. FILING DATE		LING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/750,489	12/31/2003		Ki-Min Lee	20059/PIA31071	1804
34431	7590	10/28/2005		EXAM	IINER
HANLEY,	FLIGHT	& ZIMMERMAN	LEE, CALVIN		
20 N. WACKER DRIVE SUITE 4220				ART UNIT	PAPER NUMBER
CHICAGO, IL 60606				2818	

DATE MAILED: 10/28/2005

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)	
	10/750,489	LEE, KI-MIN	
Office Action Summary	Examiner	Art Unit	
	Lee, Calvin	2818	
The MAILING DATE of this communication Period for Reply	n appears on the cover sheet wi	th the correspondence address	
A SHORTENED STATUTORY PERIOD FOR R THE MAILING DATE OF THIS COMMUNICATI - Extensions of time may be available under the provisions of 37 C after SIX (6) MONTHS from the mailing date of this communication - If the period for reply specified above is less than thirty (30) days, - If NO period for reply is specified above, the maximum statutory properties to reply within the set or extended period for reply will, by Any reply received by the Office later than three months after the earned patent term adjustment. See 37 CFR 1.704(b).	ON. FR 1.136(a). In no event, however, may a roon. a reply within the statutory minimum of thirt period will apply and will expire SIX (6) MON statute, cause the application to become AB	eply be timely filed y (30) days will be considered timely. THS from the mailing date of this communication. ANDONED (35 U.S.C. § 133).	
Status			
1) ☐ Responsive to communication(s) filed on 2a) ☐ This action is FINAL.	This action is non-final.	• •	
Disposition of Claims			
4) ☐ Claim(s) 1.3-7 and 9-15 is/are pending in 4a) Of the above claim(s) is/are wit 5) ☐ Claim(s) is/are allowed. 6) ☐ Claim(s) 1.3-7 and 9-15 is/are rejected. 7) ☐ Claim(s) is/are objected to. 8) ☐ Claim(s) are subject to restriction as	hdrawn from consideration.		
Application Papers			
9) ☐ The specification is objected to by the Exa 10) ☑ The drawing(s) filed on 31 December 2003 Applicant may not request that any objection to Replacement drawing sheet(s) including the country. The oath or declaration is objected to by the	3 is/are: a)⊠ accepted or b)☐ o the drawing(s) be held in abeyan orrection is required if the drawing(ce. See 37 CFR 1.85(a). s) is objected to. See 37 CFR 1.121(d).	
Priority under 35 U.S.C. § 119			
12) Acknowledgment is made of a claim for for a) All b) Some * c) None of: 1. Certified copies of the priority docur 2. Certified copies of the priority docur 3. Copies of the certified copies of the application from the International But * See the attached detailed Office action for a	ments have been received. ments have been received in A priority documents have been ureau (PCT Rule 17.2(a)).	pplication No received in this National Stage	
Attachment(s) 1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449 or PTO/S Paper No(s)/Mail Date	Paper No(s	ummary (PTO-413))/Mail Date formal Patent Application (PTO-152)	

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OFFICE ACTION

Response to Amendment

1. The cancellation of claims 2 & 8 and the amendment of claims 1 & 7 dated October 12, 2005 are acknowledged.

Claim Rejections - 35 U.S.C. § 102

- 2. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 (e) that form the basis for the rejections under this section made in this Office action:
- (e) the invention was described in a patent granted on an application for patent by another filed in the United States before the invention thereof by the applicant for patent, or on an international application by another who has fulfilled the requirements of paragraphs (1), (2), and (4) of section 371(c) of this title before the invention thereof by the applicant for patent.
- 3. Claims 1, 3, 5-7, 9-10, and 12-13 are rejected under 35 US.C 102(e) as being anticipated by *Rasmussen* (US 2004/0262658).
- a) In re claims 1 and 7, *Rasmussen* discloses a method of fabricating an MIM capacitor of high capacitance in a semiconductor device, the method comprising the steps of:
- -depositing an interlayer dielectric film 25 of PSG or TEOS on a metal line 50, 52 [¶ 0039]
- -planarizing the interlayer dielectric film (see the flat top surface of the dielectric film in Fig. 9)
- -etching the dielectric film to form a capacitor-forming region 41 [Fig. 10]
- -sequentially depositing a lower electrode 71 [¶ 0042], an insulator layer 72 [¶ 0043], and an upper electrode 73 [¶ 0044] on the interlayer dielectric film;

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-etching the lower electrode, the insulator layer, and the upper electrode to form the MIM capacitor [Fig. 11], wherein a capacitance of the MIM capacitor is determined by controlling a

thickness of the interlayer dielectric film [¶ 0043].

b) In re claim 3, Rasmussen also suggests that the interlayer dielectric film is made of BPSG,

PSG or TEOS [¶0039].

c) In re claims 5 and 12, Rasmussen suggests the insulator layer made of Ta₂O₅, Al₂O₃, Si₃N₄.

d) In re claims 6 and 13, Rasmussen suggests that the upper electrode is made of osmium, Pt,

rhodium, Ru, palladium, or iridium [¶0044].

e) In re claims 9 and 10, Rasmussen suggests that the interlayer dielectric layer is planarized

by CMP or dry etch (i.e., etch back) [¶ 0043].

Claim Rejections - 35 U.S.C. § 103

4. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all

obviousness rejections set forth in this Office Action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as

set forth in section 102 of this title, if the differences between the subject matter sought to be

patented and the prior art are such that the subject matter as a whole would have been obvious at

the time the invention was made to a person having skills in the art to which said subject matter

pertains. Patentability shall not be negatived by the manner in which the invention was made.

5. Claims 4, 11, and 14-15 are rejected under 35 US.C 103(a) as being unpatentable over

Rasmussen in view of Lopatin et al (US 6,433,379).

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a) In re claims 4 and 11, *Rasmussen* suggests the lower electrode made of Os, Pt, Rh, Ru, Pd or Ir, but not any one of Ti, W or TiN. *Lopatin et al* teaches a same method of fabricating an MIM

capacitor of high capacitance, with a lower electrode 40 made of Ta, Ti, W, etc. [col. 4, ln.60].

It would have been obvious to one having skills in the art to combine the teachings of Rasmussen and Lopatin et al, and thus arrive at the claimed invention, since it has been held to be within the general skill of a worker in the art to select a known material on the basis of its suitability for the intended use as a matter of obvious design choice. In re Leshin, 125 SUPQ 416. Moreover, it appears as if any electrode material including the claimed materials would work equivalently to any other well-known electrode material as long as the preferable electrode material has a desired conductive characteristic.

b) In re claims 14-15, *Rasmussen* is silent about the lower electrode, the insulator layer and the upper electrode being planarized by CMP (or by an etch-back process). *Lopatin et al* suggests that the capacitor structure 10' is planarized by CMP or etch back [Fig. 9 and col. 7].

It would have been obvious to one having skills in the art to have modified the process of *Rasmussen* by utilizing a CMP to planarize the capacitor structure for the purpose of forming a capacitor within its capacitor trench.

Response to Argument

6. After a closer review of the Applicant's argument (dated October 12, 2005) and after further search related arts (including the previous cited art, *Rasmussen'* 658) the examiner has realized that *Rasmussen* would read on at least claims 1 and 7 and the allowed feature (i.e., capacitance determined by controlling insulator thickness). Therefore, above is a new ground of rejections, which the Examiner relies on to reject the pending claims.

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Contact Information

7. Any inquiry concerning this communication from the Examiner should be directed to

Calvin Lee at (571) 272-1896 on Mondays thru Thursdays 6:30-4:30PM. If attempts to reach the

examiner by telephone are unsuccessful, Art Unit 2818's Supervisory Patent Examiner David

Nelms can be reached at (571) 272-1787. The fax phone number for the organization (where this

application is assigned to) is (571) 273-8300.

Information regarding the status of an application may be obtained from the Patent

Application Information Retrieval (PAIR) system at http://pair-direct.uspto.gov. Should you have

questions on access to the PAIR system, contact the Electronic Business Center at (866) 217-9197.

Calvin Lee

Date: October 25, 2005

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